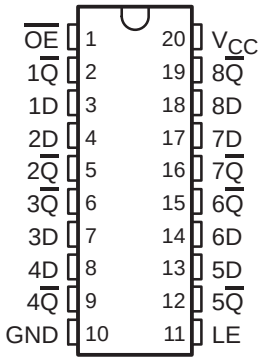
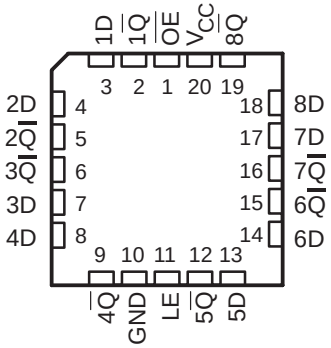
- **State-of-the-Art *EPIC*-II*B*™ BiCMOS Design Significantly Reduces Power Dissipation**
- **Latch-Up Performance Exceeds 500 mA Per JEDEC Standard JESD-17**
- **Typical V_{OLP} (Output Ground Bounce) < 1 V at V_{CC} = 5 V, T_A = 25°C**
- **High-Drive Outputs (–32-mA I_{OH}, 64-mA I_{OL})**
- **Package Options Include Plastic Small-Outline (DW) and Shrink Small-Outline (DB) Packages, Ceramic Chip Carriers (FK), and Plastic (N) and Ceramic (J) DIPs**

SN54ABT533 . . . J PACKAGE
SN74ABT533 . . . DB, DW, OR N PACKAGE
(TOP VIEW)



SN54ABT533 . . . FK PACKAGE
(TOP VIEW)



description

The ′ABT533 are 8-bit transparent D-type latches with 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. They are particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

When the latch-enable (LE) input is high, the $\overline{Q}$ outputs follow the complements of the data (D) inputs. When LE is taken low, the $\overline{Q}$ outputs are latched at the inverse of the levels set up at the D inputs. The ′ABT533 provides inverted data at its outputs.

A buffered output-enable ($\overline{OE}$) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or a high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and the increased drive provide the capability to drive bus lines without need for interface or pullup components.

$\overline{OE}$ does not affect the internal operations of the latches. Previously stored data can be retained or new data can be entered while the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN74ABT533 is available in TI's shrink small-outline package (DB), which provides the same I/O pin count and functionality of standard small-outline packages in less than half the printed-circuit-board area.

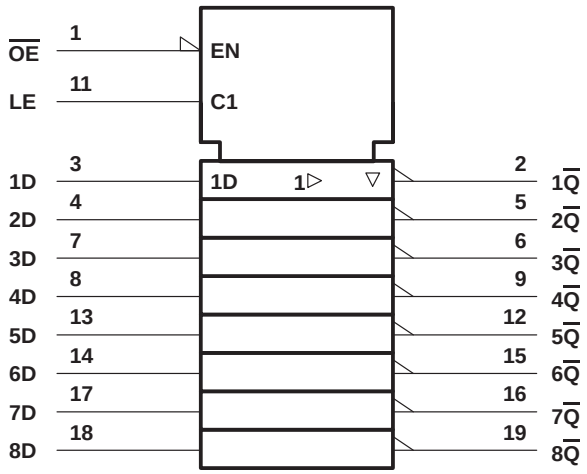
The SN54ABT533 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74ABT533 is characterized for operation from –40°C to 85°C.

EPIC-IIB is a trademark of Texas Instruments Incorporated.

FUNCTION TABLE
(each latch)

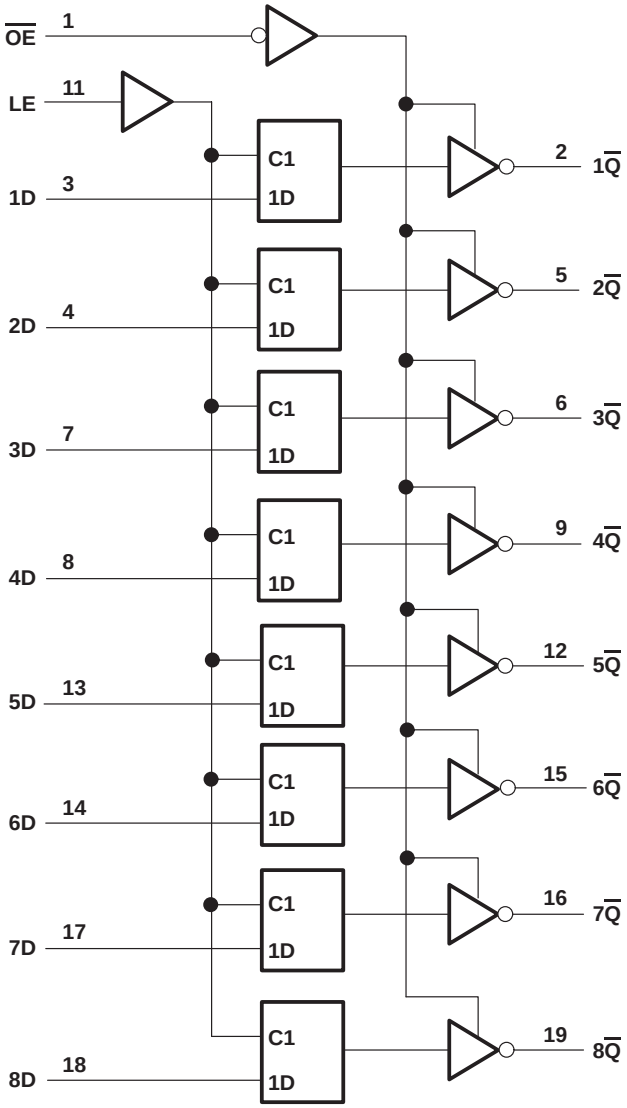
INPUTS			OUTPUT
$\overline{OE}$	LE	D	$\overline{Q}$
L	H	H	L
L	H	L	H
L	L	X	$\overline{Q}_0$
H	X	X	Z

logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V_{CC} . . . . . –0.5 V to 7 V
Input voltage range, V_I (see Note 1) . . . . . –0.5 V to 7 V
Voltage range applied to any output in the high state or power-off state, V_O . . . . . –0.5 V to 5.5 V
Current into any output in the low state, I_O: SN54ABT533 . . . . . 96 mA
SN74ABT533 . . . . . 128 mA
Input clamp current, I_{IK} (V_I < 0) . . . . . –18 mA
Output clamp current, I_{OK} (V_O < 0) . . . . . –50 mA
Maximum power dissipation at T_A = 55°C (in still air) (see Note 2): DB package . . . . . 0.6 W
DW package . . . . . 1.6 W
N package . . . . . 1.3 W
Storage temperature range . . . . . –65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
2. The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils, except for the N package, which has a trace length of zero. For more information, refer to the *Package Thermal Considerations* application note in the 1994 *ABT Advanced BiCMOS Technology Data Book*, literature number SCBD002B.

recommended operating conditions (see Note 3)

		SN54ABT533		SN74ABT533		UNIT
		MIN	MAX	MIN	MAX	
V_{CC}	Supply voltage	4.5	5.5	4.5	5.5	V
V_{IH}	High-level input voltage	2		2		V
V_{IL}	Low-level input voltage		0.8		0.8	V
V_I	Input voltage	0	V_{CC}	0	V_{CC}	V
I_{OH}	High-level output current		–24		–32	mA
I_{OL}	Low-level output current		48		64	mA
$\Delta t/\Delta v$	Input transition rise or fall rate		10		10	ns/V
T_A	Operating free-air temperature	–55	125	–40	85	°C

NOTE 3: Unused or floating inputs must be held high or low.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS			T_A = 25°C			SN54ABT533		SN74ABT533		UNIT
				MIN	TYP†	MAX	MIN	MAX	MIN	MAX	
V_{IK}	V_{CC} = 4.5 V,	I_I = –18 mA				–1.2		–1.2		–1.2	V
V_{OH}	V_{CC} = 4.5 V,	I_{OH} = –3 mA		2.5			2.5		2.5		V
	V_{CC} = 5 V,	I_{OH} = –3 mA		3			3		3		
	V_{CC} = 4.5 V	I_{OH} = –24 mA		2			2				
		I_{OH} = –32 mA		2*					2		
V_{OL}	V_{CC} = 4.5 V	I_{OL} = 48 mA				0.55		0.55			V
		I_{OL} = 64 mA				0.55*				0.55	
I_I	V_{CC} = 5.5 V,	V_I = V_{CC} or GND				±1		±1		±1	µA
I_{OZH}	V_{CC} = 5.5 V,	V_O = 2.7 V				10‡		10‡		10‡	µA
I_{OZL}	V_{CC} = 5.5 V,	V_O = 0.5 V				–10‡		–10‡		–10‡	µA
I_{off}	V_{CC} = 0,	V_I or V_O ≤ 4.5 V				±150				±150	µA
I_{CEX}	V_{CC} = 5.5 V,	V_O = 5.5 V	Outputs high			50		50		50	µA
I_O§	V_{CC} = 5.5 V,	V_O = 2.5 V		–50	–140	–180	–50	–180	–50	–180	mA
I_{CC}	V_{CC} = 5.5 V, I_O = 0, V_I = V_{CC} or GND		Outputs high		1	250		250		250	µA
			Outputs low		24	30		30		30	mA
			Outputs disabled		0.5	250		250		250	µA
ΔI_{CC}¶	V_{CC} = 5.5 V, One input at 3.4 V, Other inputs at V_{CC} or GND		Outputs enabled			1.5		1.5		1.5	mA
			Outputs disabled			1.5		1.5		1.5	
			Control inputs			1.5		1.5		1.5	
C_i	V_I = 2.5 V or 0.5 V				3						pF
C_o	V_O = 2.5 V or 0.5 V				9						pF

* On products compliant to MIL-STD-883, Class B, this parameter does not apply.
† All typical values are at V_{CC} = 5 V.
‡ This data sheet limit may vary among suppliers.
§ Not more than one output should be tested at a time, and the duration of the test should not exceed one second.
¶ This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

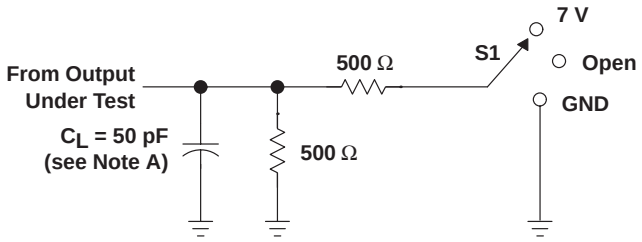
timing requirements over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure1)

			V_{CC} = 5 V, T_A = 25°C		SN54ABT533		SN74ABT533		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
t_w	Pulse duration, LE high		3.3		3.3		3.3		ns
t_{su}	Setup time, data before LE↓	High or low	2.1		2.1		2.1		ns
t_h	Hold time, data after LE↓	High or low	1.5§		1.5§		1.5§		ns

switching characteristics over recommended ranges of supply voltage and operating free-air temperature, C_L = 50 pF (unless otherwise noted) (see Figure 1)

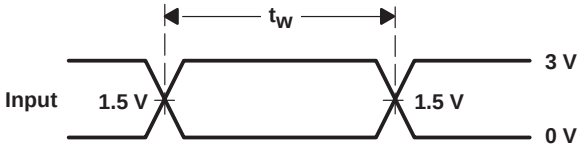
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC} = 5 V, T_A = 25°C			SN54ABT533		SN74ABT533		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t_{PLH}	D	$\overline{Q}$	1.9	4.2	5.4	1.9	6.7	1.9	6.4	ns
t_{PHL}			3.1	4.9	6.3	3.1	6.9	3.1	6.6	
t_{PLH}	LE	$\overline{Q}$	2.7	4.9	6.2	2.7	7.6	2.7	7.3	ns
t_{PHL}			3.5	5.4	6.8	3.5	7.5	3.5	7.3	
t_{PZH}	$\overline{OE}$	$\overline{Q}$	1.6	3.7	4.8	1.6	5.8	1.6	5.7	ns
t_{PZL}			2.4	4.2	6.2	2.4	6.9	2.4	6.7	
t_{PHZ}	$\overline{OE}$	$\overline{Q}$	2.8	5.1	6.2	2.8	7.2	2.8	6.9	ns
t_{PLZ}			2	4.1	6	2	6.9	2	6.5	

PARAMETER MEASUREMENT INFORMATION

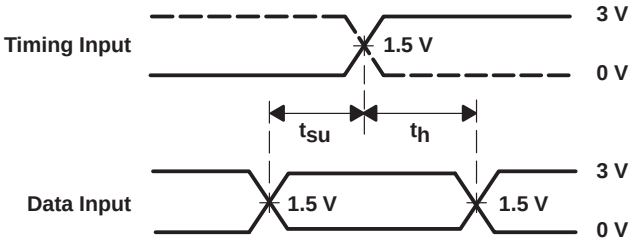


TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	7 V
t_{PHZ}/t_{PZH}	Open

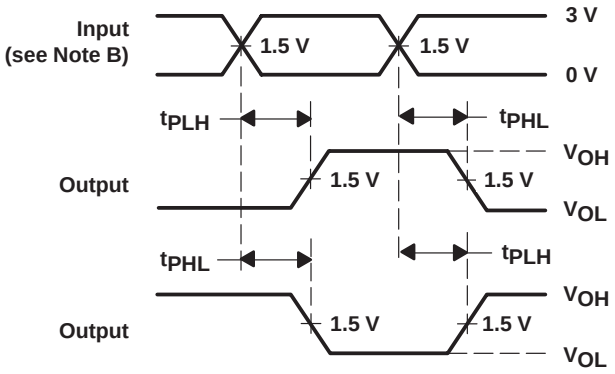
LOAD CIRCUIT FOR OUTPUTS



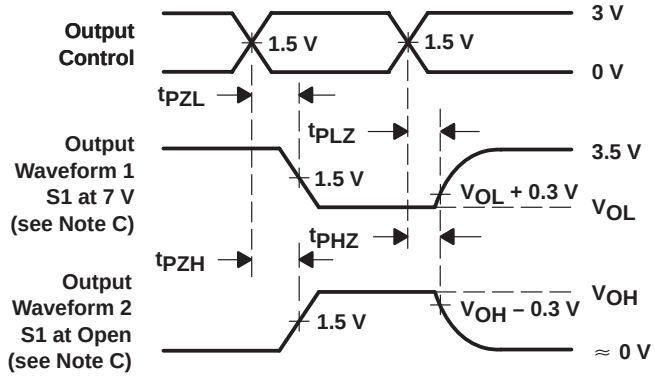
VOLTAGE WAVEFORMS
PULSE DURATION



VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
INVERTING AND NONINVERTING OUTPUTS



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES
LOW- AND HIGH-LEVEL ENABLING

NOTES: A. C_L includes probe and jig capacitance.
B. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω, t_r ≤ 2.5 ns, t_f ≤ 2.5 ns.
C. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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PRODUCT FOLDER | PRODUCT INFO: FEATURES | DESCRIPTION | DATASHEETS | PRICING/AVAILABILITY/PKG | APPLICATION NOTES | USER GUIDES | MORE LITERATURE

PRODUCT SUPPORT: TRAINING

SN54ABT533, Octal Transparent D-type Latches With 3-State Outputs

DEVICE STATUS: **ACTIVE**

PARAMETER NAME	SN54ABT533
Voltage Nodes (V)	5

FEATURES

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- State-of-the-Art *EPIC-II B*™ BiCMOS Design Significantly Reduces Power Dissipation
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- Typical V_{OLP} (Output Ground Bounce)
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DESCRIPTION

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TECHNICAL DOCUMENTS

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To view the following documents, Acrobat Reader 4.0 is required.
To download a document to your hard drive, right-click on the link and choose 'Save'.

DATASHEET

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Full datasheet in Acrobat PDF: sn54abt533.pdf (122 KB,Rev.A) (Updated: 07/01/1994)

APPLICATION NOTES

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Product Folder: SN54ABT533, Octal Transparent D-type Latches With 3-State Outputs

View Application Notes for Digital Logic

- Advanced BiCMOS Technology (ABT) Logic Characterization Information (Rev. B) (SCBA008B - Updated: 06/01/1997)
- Advanced BiCMOS Technology (ABT) Logic Enables Optimal System Design (Rev. A) (SCBA001A - Updated: 03/01/1997)
- Bus-Interface Devices With Output-Damping Resistors Or Reduced-Drive Outputs (Rev. A) (SCBA012A - Updated: 08/01/1997)
- Designing With Logic (Rev. C) (SDYA009C - Updated: 06/01/1997)
- Evaluation of Nickel/Palladium/Gold-Finished Surface-Mount Integrated Circuits (SZZA026 - Updated: 06/20/2001)
- Family of Curves Demonstrating Output Skews for Advanced BiCMOS Devices (Rev. A) (SCBA006A - Updated: 12/01/1996)
- Implications of Slow or Floating CMOS Inputs (Rev. C) (SCBA004C - Updated: 02/01/1998)
- Input and Output Characteristics of Digital Integrated Circuits (SDYA010 - Updated: 10/01/1996)
- Live Insertion (SDYA012 - Updated: 10/01/1996)
- Power-Up 3-State (PU3S) Circuits in TI Standard Logic Devices (SZZA033 - Updated: 05/10/2002)
- Quad Flatpack No-Lead Logic Packages (Rev. C) (SCBA017C - Updated: 11/22/2002)
- TI IBIS File Creation, Validation, and Distribution Processes (SZZA034 - Updated: 08/29/2002)
- Understanding Advanced Bus-Interface Products Design Guide (SCAA029, 253 KB - Updated: 05/01/1996)
- Understanding and Interpreting Texas Instruments Standard-Logic Products Data Sh (Rev. A) (SZZA036A - Updated: 02/27/2003)

MORE LITERATURE

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- Enhanced Plastic Portfolio Brochure (SGZB004, 387 KB - Updated: 08/19/2002)
- Logic Reference Guide (SCYB004, 1032 KB - Updated: 10/23/2001)
- MicroStar Junior BGA Design Summary (SCET004, 167 KB - Updated: 07/28/2000)
- Military Brief (SGYN138, 803 KB - Updated: 10/10/2000)
- Overview of IEEE Std 91-1984, Explanation of Logic Symbols Training Booklet (Rev. A) (SDYZ001A, 138 KB - Updated: 07/01/1996)
- Palladium Lead Finish User's Manual (SDYV001, 2041 KB - Updated: 11/01/1996)
- QML Class V Space Products Military Brief (Rev. A) (SGZN001A, 257 KB - Updated: 10/07/2002)

USER GUIDES

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- LOGIC Pocket Data Book (SCYD013, 4837 KB - Updated: 12/05/2002)

PRICING/AVAILABILITY/PKG

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DEVICE INFORMATION
Updated Daily

TI INVENTORY STATUS
As Of 09:00 AM GMT, 17 Apr 2003

REPORTED DISTRIBUTOR INVENTORY
As Of 09:00 AM GMT, 17 Apr 2003

ORDERABLE DEVICE	STATUS	PACKAGE TYPE | PINS	TEMP (°C)	DSCC NUMBER	PRODUCT CONTENT	BUDGETARY PRICING QTY | $US	STD PACK QTY	IN STOCK	IN PROGRESS QTY | DATE	LEAD TIME	DISTRIBUTOR COMPANY | REGION	IN STOCK	PURCHASE
5962-9584301Q2A	ACTIVE	LCCC (FK) | 20	-55 TO 125		View Contents	1KU | 14.60	1	131*	3770 | 20 May	8 WKS	None Reported View Distributors		
									>10k | 27 May				
5962-9584301QRA	ACTIVE	CDIP (J) | 20	-55 TO 125		View Contents	1KU | 8.34	1	1*	>10k | 20 May	8 WKS	None Reported View Distributors		
5962-9584301QSA	ACTIVE	CFP (W) | 20	-55 TO 125		View Contents	1KU | 12.16	1	0*	>10k | 20 May	8 WKS	None Reported View Distributors		
SNJ54ABT533FK	ACTIVE	LCCC (FK) | 20	-55 TO 125	5962-9584301Q2A	View Contents	1KU | 14.60	1	0*	3889 | 20 May	8 WKS	None Reported View Distributors		
									>10k | 27 May				
SNJ54ABT533J	ACTIVE	CDIP (J) | 20	-55 TO 125	5962-9584301QRA	View Contents	1KU | 8.34	1	124*	9668 | 20 May	8 WKS	None Reported View Distributors		
									>10k | 27 May				

Product Folder: SN54ABT533, Octal Transparent D-type Latches With 3-State Outputs

SNJ54ABT533W	ACTIVE	CFP (W) | 20	-55 TO 125	5962-9584301QSA	View Contents	1KU | 12.16	1	0*	9786 | 20 May	8 WKS	None Reported View Distributors		
									>10k | 27 May				

Table Data Updated on: 4/17/2003